Power Transistors Panasonic

2SC3611

Silicon NPN epitaxial planar type

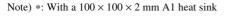
For video amplifier

■ Features

- High transition frequency f_T
- \bullet Small collector output capacitance C_{ob}
- Wide current range
- TO-126B package which requires no insulation plate for installation to the heat sink

■ Absolute Maximum Ratings $T_C = 25$ °C

| Parameter | | Symbol | Rating | Unit |
|------------------------------|---------------------|------------------|-------------|------|
| Collector to base voltage | | V_{CBO} | 110 | V |
| Collector to emitter voltage | | V _{CER} | 100 | V |
| | | V _{CEO} | 50 | V |
| Emitter to base voltage | | V _{EBO} | 3.5 | V |
| Peak collector current | | I_{CP} | 300 | mA |
| Collector current | | I_{C} | 150 | mA |
| Collector power | $T_C = 25^{\circ}C$ | P _C | 1.2 | W |
| dissipation | $T_a = 25^{\circ}C$ | | 4.0 * | |
| Junction temperature | | T _j | 150 | °C |
| Storage temperature | | T_{stg} | -55 to +150 | °C |



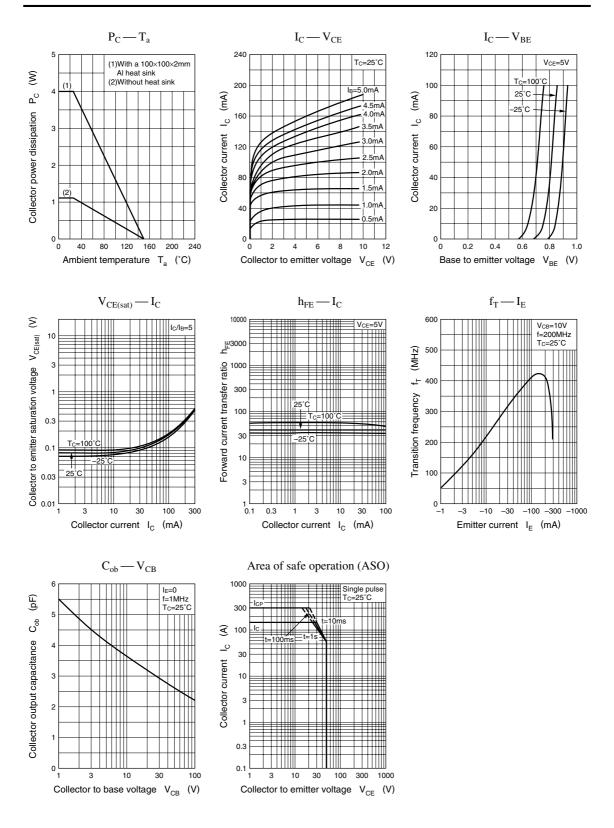
Unit: mm 8.0^{+0.5} 9.3.16±0.1 0.75±0.1 0.5±0.1 1.76±0.1 4.6±0.2 1: Base 2: Collector 3: Emitter TO-126B-Al Package

■ Electrical Characteristics $T_C = 25$ °C

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|---|----------------------|---|-----|-----|-----|------|
| Collector cutoff current | I_{CEO} | $V_{CE} = 35 \text{ V}, I_{B} = 0$ | | | 10 | μΑ |
| Collector to base voltage | V_{CBO} | $I_C = 100 \mu\text{A}, I_E = 0$ | 110 | | | V |
| Collector to emitter voltage | V _{CER} | $I_C = 500 \ \mu A, R_{BE} = 470 \ \Omega$ | 100 | | | V |
| | V _{CEO} | $I_C = 1 \text{ mA}, I_B = 0$ | 50 | | | V |
| Emitter to base voltage | V_{EBO} | $I_E = 100 \mu\text{A}, I_C = 0$ | 3.5 | | | V |
| Forward current transfer ratio | h_{FE} | $V_{CE} = 5 \text{ V}, I_{C} = 100 \text{ mA}$ | 20 | | | |
| Collector to emitter saturation voltage | V _{CE(sat)} | $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ | | | 0.5 | V |
| Transition frequency | f_{T1} | $V_{CB} = 10 \text{ V}, I_E = -10 \text{ mA}, f = 200 \text{ MHz}$ | | 300 | | MHz |
| | f_{T2} | $V_{CB} = 10 \text{ V}, I_E = -110 \text{ mA}, f = 200 \text{ MHz}$ | | 350 | | MHz |
| Collector output capacitance | C _{ob} | $V_{CB} = 30 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$ | | 3 | | pF |

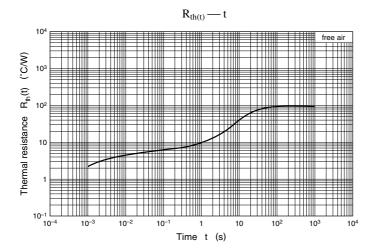
Panasonic 201

2SC3611 Power Transistors



202 Panasonic

Power Transistors 2SC3611



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